## 2SD2528

## Silicon NPN epitaxial planar type

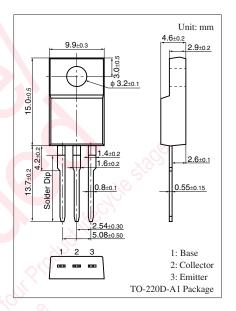
For power amplification and high-current amplification

#### ■ Features

- High forward current transfer ratio h<sub>FE</sub>
- Satisfactory linearity of forward current transfer ratio h<sub>FE</sub>
- Full-pack package which can be installed to the heat sink with one screw

### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter		Symbol	Rating	Unit	
Collector-base voltage (En	$V_{CBO}$	80	V		
Collector-emitter voltage	V <sub>CEO</sub>	60	V		
Emitter-base voltage (Collector open)		$V_{EBO}$	6	V	
Collector current		$I_{C}$	5	A	
Peak collector current		$I_{CP}$	10	A	
Base current		$I_{B}$	1	A	
Collector power	$T_C = 25^{\circ}C$	P <sub>C</sub>	40	W	
dissipation			2.0	100	
Junction temperature		$T_{j}$	150	°C	
Storage temperature		$T_{stg}$	-55 to +150	°C C	
			1 / /	141	



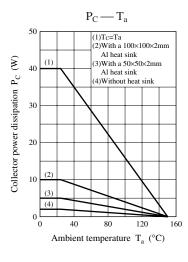
### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

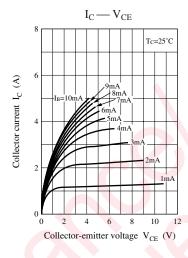
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_C = 25 \text{ mA}, I_B = 0$	60	0.		V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 80 \text{ V}, I_{E} = 0$	7 60.		100	μΑ
Emitter-base cutoff current (Collector open)	$I_{EBO}$	$V_{EB} = 6 \text{ V}, I_C = 0$			100	μΑ
Forward current transfer ratio	h <sub>FE</sub> *	$V_{CE} = 4 \text{ V}, I_{C} = 1 \text{ A}$	500		2000	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 4 \text{ A}, I_B = 0.1 \text{ A}$			0.3	V
Transition frequency	$f_T$	$V_{CE} = 12 \text{ V}, I_{C} = 0.4 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time	t <sub>on</sub>	$I_C = 4 \text{ A}, I_{B1} = 0.08 \text{ A}, I_{B2} = -0.08 \text{ A}$		0.4		μs
Storage time	t <sub>stg</sub>	$V_{CC} = 50 \text{ V}$		2.0		μs
Fall time	$t_{\rm f}$	<i>♦</i> //		0.6		μs

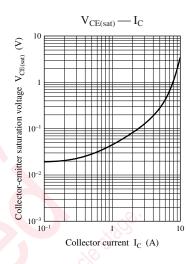
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

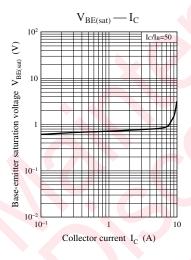
#### 2. \*: Rank classification

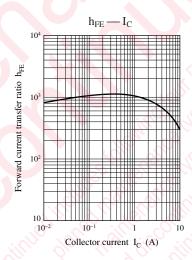
Rank	Q	Р		
h <sub>FE1</sub>	500 to 1 200	800 to 2000		

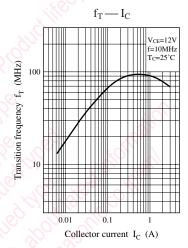


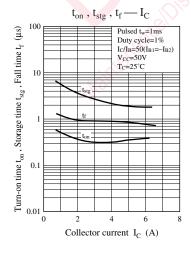


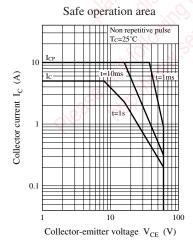












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